AUTOMOTIVE

RoHS

COMPLIANT HALOGEN

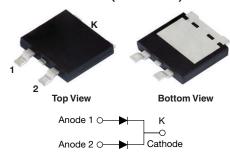
FREE



Vishay Semiconductors

Hyperfast Rectifier, 2 x 15 A FRED Pt®

eSMP[®] Series SMPD (TO-263AC)



LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS				
I _{F(AV)}	2 x 15 A			
V _R	600 V			
V _F at I _F (T _J = 150 °C)	1.22 V			
t _{rr}	30 ns			
T _J max.	175 °C			
Package	SMPD (TO-263AC)			
Circuit configuration	Common cathode			

FEATURES

- Hyperfast recovery time, reduced Q_{rr}, and soft recovery
- 175 °C maximum operating junction temperature
- For PFC CRM, snubber operation
- Low forward voltage drop
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified, meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see <u>www.vishav.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

State of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop and ultrafast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness, and reliability characteristics.

These devices are intended for use in PFC, boost, lighting, in the AC/DC section of SMPS, freewheeling and clamp diodes.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element and snubbers.

MECHANICAL DATA

Case: SMPD (TO-263AC)

Molding compound meets UL 94 V-0 flammability rating

Halogen-free, RoHS-compliant

Terminals: matte tin plated leads, solderable per

J-STD-002

ABSOLUTE MAXIMUM RATINGS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Peak repetitive reverse voltage		V_{RRM}		600	V
A	per device	I _{F(AV)} (1)	T _C = 130 °C	30	
Average rectified forward current	per diode			15	Α
Non-repetitive peak surge current, per diode		I _{FSM}	T _J = 25 °C, 10 ms sine pulse	160	

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V_{BR} , V_{R}	I _R = 100 μA	600	-	-	
Forward voltage, per diode	V _E	I _F = 15 A	-	1.63	2.15	V
	VF	I _F = 15 A, T _J = 150 °C	-	1.22	1.65	
Reverse leakage current, per diode	_	V _R = V _R rated	-	-	20	μА
	IR	$T_J = 150 ^{\circ}\text{C}, V_R = V_R \text{rated}$	-	-	500	
Junction capacitance, per diode	C _T	V _R = 600 V	-	16	-	pF

Note

(1) Mounted on infinite heatsink



DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
		$I_F = 1 A, dI_F/dt = 50 A$	√μs, V _R = 30 V	-	30	-	
Reverse recovery time per diode		$I_F = 0.5 \text{ A}, I_R = 1 \text{ A}, I_{rr} = 0.25 \text{ A}$		-	-	30	
	t _{rr}	T _J = 25 °C		-	41	-	ns
		T _J = 125 °C		=.	92	-	
Dook recovery ourrent per diede		T _J = 25 °C	$I_F = 15 \text{ A},$ $dI_F/dt = 500 \text{ A/}\mu\text{s},$ $V_R = 400 \text{ V}$	-	7	-	^
Peak recovery current per diode I _{RRM}	IRRM	T _J = 125 °C		-	13	-	A
Payaraa raaayan, aharaa par diada	viewee weeklers above mer diede	T _J = 25 °C		-	150	-	nC
Reverse recovery charge per diode	Q _{rr}	T _J = 125 °C		-	590	-	110

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	+175	°C
Thermal resistance, junction to mount, per diode	R_{thJM}		-	1.2	1.7	°C/W
Approximate weight				0.55		g
Approximate weight				0.02		oz.
Marking device		Case style SMPD (TO-263AC)		30CI	DH06	

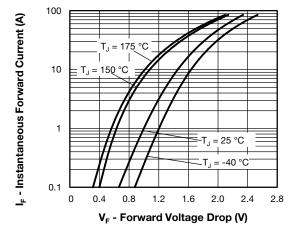


Fig. 1 - Typical Forward Voltage Drop Characteristics, Per Diode

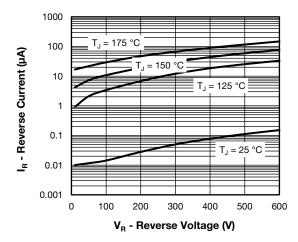


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage, Per Diode

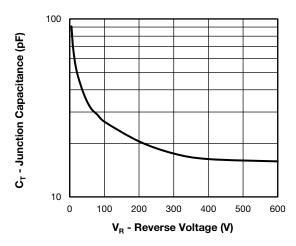


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage, Per Diode

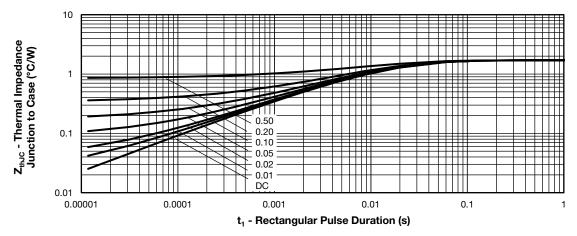


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics, Per Diode

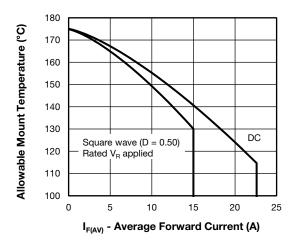


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current, Per Diode

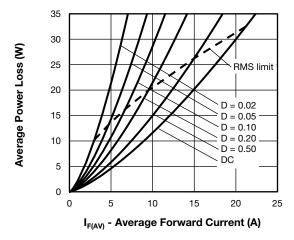


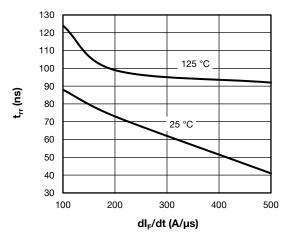
Fig. 6 - Forward Power Loss Characteristics, Per Diode

Note

Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{th,JC}$; $Pd = forward power loss = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 5)}$; $Pd_{REV} = inverse power loss = V_{R1} \times I_{R} (1 - D)$; $I_{R} \text{ at } V_{R1} = \text{rated } V_{R}$

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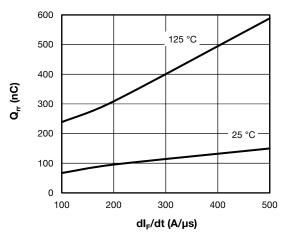
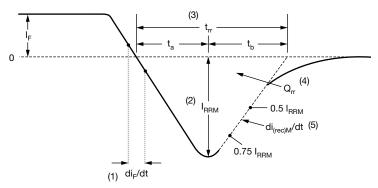


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt Per Diode

Fig. 8 - Typical Stored Charge vs. dI_F/dt Per Diode



- (1) di_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) t_{rr} reverse recovery time measured from zero crossing point of negative going I_{F} to point where a line passing through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current.
- (4) $\mathbf{Q}_{\rm rr}$ area under curve defined by $\mathbf{t}_{\rm rr}$ and $\mathbf{I}_{\rm RRM}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

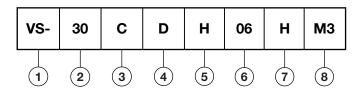
(5) di_{(rec)M}/dt - peak rate of change of current during t_b portion of t_{rr}

Fig. 9 - Reverse Recovery Waveform and Definitions



ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (30 A)

Circuit configuration:

C = common cathode

4 - D = SMPD package

5 - Process type,

H = hyperfast recovery

6 - Voltage code (06 = 600 V)

7 - H = AEC-Q101 qualified

8 - M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)							
PREFERRED P/N	REFERRED P/N QUANTITY PER REEL MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION						
VS-30CDH06HM3/I (1)	2000	2000	13" diameter plastic tape and reel				

Note

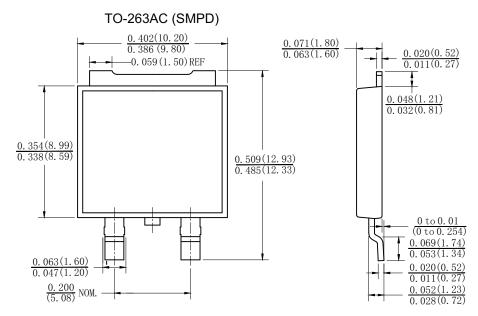
(1) AEC-Q101 qualified

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95604			
Part marking information	www.vishay.com/doc?95566			
Packaging information	www.vishay.com/doc?88869			
SPICE model	www.vishay.com/doc?96776			

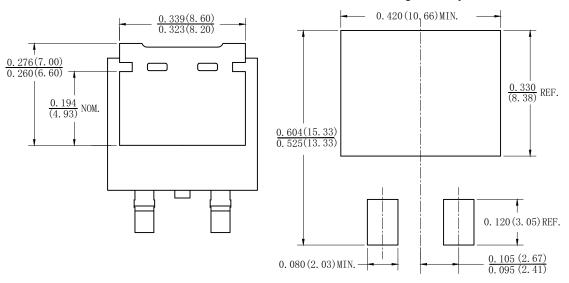


TO-263AC (SMPD)

DIMENSIONS in inches (millimeters)



Mounting Pad Layout





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Vishay

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